

Ref. No.: Ex/PG/MET/PC/T/111/2025

M.TECH MATERIAL ENGG FIRST YEAR FIRST SEMESTER - 2025

Subject: MATERIALS SCIENCE

Time: 3 hours

Full Marks = 100

(Answer All the Questions)		COs
1. Explain the any two terms with examples: ($2.5 \times 2 = 5$) <i>a.</i> Bravais lattice <i>b.</i> Unit cell <i>c.</i> Coordination number 2. Calculate the atomic packing factor (APF) for: (Answer any two: $2.5 \times 2 = 5$) <i>a.</i> Face-centered cubic (FCC) structure. <i>b.</i> Body-centered cubic (BCC) structure. <i>c.</i> Hexagonal close-packed (HCP) structure. 3. Sketch the following planes and directions in a cubic unit cell: ($2.5 \times 2 = 5$) <i>a.</i> (100), (110), (111) planes. <i>b.</i> [100], [110], [111] directions. 4. Explain how bond energy and bond length influence the following properties: (Answer any two: $2.5 \times 2 = 5$) <i>a.</i> Melting point <i>b.</i> Electrical conductivity <i>c.</i> Mechanical strength. 5. Explain why covalent bonds are directional, while metallic bonds are non-directional. How does this affect material behavior? (5)		CO1
6. Answer question “a” any three from others: ($10 + 5 \times 3 = 25$) <i>a.</i> Classify crystal defects and explain their generation mechanisms. (10) <i>b.</i> Compare and contrast edge dislocations and screw dislocations using diagrams. (5) <i>c.</i> Describe the mechanism of dislocation motion (glide and climb) in crystalline materials. (5) <i>d.</i> A material has a dislocation density of 10^{12}m^{-2}. If the total length of dislocations in a cubic crystal of side 1 mm is 10^6m, calculate the volume of the crystal and verify the dislocation density. (5) <i>e.</i> Calculate the equilibrium concentration of vacancies in copper at 1000°C, given that the activation energy for vacancy formation is 0.9 eV and the pre-exponential factor is $5 \times 10^{23} \text{m}^{-3}$. Discuss how temperature affects the concentration of vacancies. (5)		CO2

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7. Answer any two: ($5 \times 5 = 25$) <i>a.</i> Define diffusion. Explain the Kirkendall effect and its significance in materials processing. <i>b.</i> Compare and contrast the mechanisms of vacancy diffusion and interstitial diffusion. <i>c.</i> Derive Fick's first law of diffusion and explain each term in the equation. <i>d.</i> Calculate the diffusion coefficient for a material at 800°C given that the pre-exponential factor $D_0 = 2 \times 10^{-5} \text{ m}^2/\text{s}$ and the activation energy $Q = 150 \text{ kJ/mol}$. <i>e.</i> Discuss how temperature affects the rate of diffusion in crystalline materials. <i>f.</i> Discuss the role of diffusion in the formation of phase transformations (e.g., precipitation hardening) in alloys.	CO3
8. Answer any five: ($5 \times 5 = 25$) <i>a.</i> Explain the difference between diamagnetic, paramagnetic, and ferromagnetic materials. Provide examples of each. <i>b.</i> Describe the concept of magnetic domains and how they contribute to the magnetization process. <i>c.</i> Explain the physical significance of the B-H loop and label its key features (saturation, remanence, coercivity). <i>d.</i> Explain the concept of hysteresis loss and its importance in the design of transformers. <i>e.</i> What are Bloch walls and Néel walls? How do they differ in terms of spin alignment? <i>f.</i> A paramagnetic material has a magnetization of $3 \times 10^5 \text{ A/m}^3$ when subjected to a magnetic field of $1.5 \times 10^4 \text{ A/m}$. Calculate its magnetic susceptibility.	CO4